



AH3522/AH3524

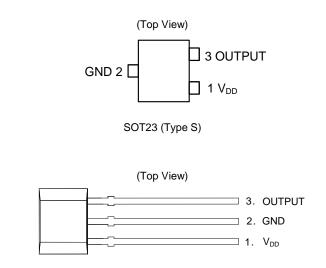
HIGH-VOLTAGE HIGH-SENSITIVITY HALL-EFFECT OMNIPOLAR SWITCH

Description

The AH3522/AH3524 is a high-voltage high-sensitivity Hall-effect Omnipolar switch IC designed for proximity, position and level sensing in consumer home appliances, office equipment, smart home to industrial applications. To support the wide range of the demanding applications, the design has been optimized to operate over the supply range of 3.0V to 28V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3522/AH3524 provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a Zener clamp on the supply. The output has an over current limit and a Zener clamp.

The single open-drain output can be switched on with South or North pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (BoP) the output is switched on (pulled low) and is held on until magnetic flux density B is lower than the release point (BRP).

Pin Assignments



SIP-3 (Ammo Pack)/SIP-3 (Bulk Pack)

Features

- Omnipolar Operation
- High Sensitivity: BoP and BRP of ±20G to ±40G and ±10G to ±25G Typical
- Single Open-Drain Output with Overcurrent Limit
- Resistant to Physical Stress
- 3.0V to 28V Operating Voltage Range
- Chopper Stabilized Design Provides
 - Superior Temperature Stability
 - Minimal Switch Point Drift
 - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Reverse Blocking Diode
- Zener Clamp on Supply and Output Pins
- -40°C to +125°C Operating Temperature
- High ESD HBM: 8kV
- Industry Standard SOT23 (Type S), SIP-3 (Ammo Pack), and SIP-3 (Bulk Pack) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

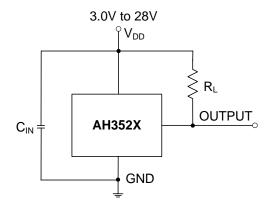
Applications

- Position and proximity sensing in home appliances, building automation, office equipment and Industrial applications
- Open and close detection
- Position detection
- Level detection
- Flow meters
- Contactless switches

- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit



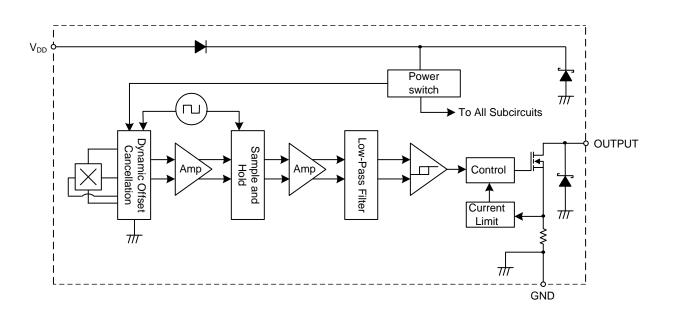
Note: 4. C_{IN} is for power stabilization and to strengthen the noise immunity. The recommended capacitance is 10nF to 100nF. R_L is the pullup resistor.

Pin Descriptions

Packages: SOT23 (Type S), SIP-3 (Ammo Pack), and SIP-3 (Bulk Pack)

Pin Number	Pin Name	Function
1	Vdd	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

Functional Block Diagram





Absolute Maximum Ratings (Notes 5 & 6) (@T_A = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit
Vdd	Supply Voltage (Note 6)		32	V
Vddr	Reverse Supply Voltage		-18	V
Vout_max	Output Pin Off Voltage (Note 6)		32	V
Іоит	Continuous Output Current		60	mA
lout_r	Reverse Output Current		-50	mA
В	Magnetic Flux Density		Unlimited	
Pp	Package Power Dissipation	SIP-3 (Ammo Pack) SIP-3 (Bulk Pack)	550	mW
		SOT23 (Type S)	230	
Ts	Storage Temperature Range		-65 to +165	°C
TJ	Maximum Junction Temperature		+150	°C
ESD HBM	Electrostatic Discharge Withstand Capability—Human Body Mo	odel	8	kV

Notes: 5. Stresses greater than those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to Absolute Maximum Ratings for extended periods can affect device reliability.

6. The absolute maximum V_{DD} of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum-rated conditions for any period of time.

Recommended Operating Conditions (@TA = -40°C to +125°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Rating	Unit
Vdd	Supply Voltage	Supply voltage, between VDD and GND pins	3.0 to 28	V
TA	Operating Temperature Range	Operating ambient temperature range	-40 to +125	°C

Electrical Characteristics (Notes 7 & 8) (@TA = -40°C to +125°C, VDD = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Vout_on	Output On Voltage	IOUT = 20mA, B > BOP	—	0.2	0.4	V
OUT_OFF	Output Leakage Current (When Output Is Off)	Vout = 28V, B < BRP, output off	_	< 0.1	10	μA
laa	Supply Current	Output open, T _A = +25°C	—	3	4	mA
ldd	Supply Current	Output open, $T_A = -40^{\circ}C$ to $+125^{\circ}C$	—	_	5	mA
	Devere Currely Current	V _{DD} = -18V, T _A = +25°C	—	-0.01	_	mA
Idd_r	Reverse Supply Current	V _{DD} = -18V, T _A = -40°C to +125°C		-0.01	1.5	mA
tp_ON	Device Power-On Time (Startup Time)	$V_{DD} \ge 3V, B > B_{OP}$ (Note 7)		10	_	μs
fc	Chopping Frequency	V _{DD} ≥ 3V	_	500		kHz
tD	Response Time Delay (Time from Magnetic Threshold Reached to the Start of the Output Rise or Fall)	(Note 9)	_	4	_	μs
tR	Output Rising Time (External Pullup Resistor RL and Load Capacitance Dependent)	$R_L = 1k\Omega$, $C_L = 20pF$ (Note 9)	_	0.2	1	μs
Output Falling Time t _F (Internal Switch Resistance and Load Capacitance Dependent)		$R_L = 1k\Omega$, $C_L = 20pF$ (Note 9)		0.1	1	μs
IOCL	Output Current Limit	B > B _{OP} (Note 10)	30	—	55	mA
Vz	Zener Clamp Voltage	$I_{DD} = 5 mA, T_A = +25 °C$	28			V

Notes: 7. When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the startup time of 10µs typical from the operating voltage reaching 3V.

 Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

9. Guaranteed by design, process control, and characterization. Not tested in production.

10. The device limits the output current I_{OUT} to current limit of I_{OCL}.



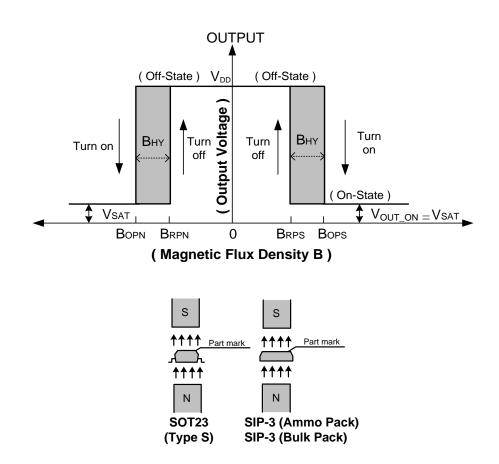
Magnetic Characteristics (Notes 11 & 12) (T _A = -40°C to +125°C, V _{DD} = 3.0V to 28V, unless	s otherwise specified)
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Part Number	Symbol	Parameter	Min	Тур	Max	Unit	Output Type
	BOPS (South Pole to the Part Marking Side)	Operation Point	8	20	30		
	B _{OPN} (North Pole to the Part Marking Side)	Operation Foint	-30	-20	-8		
AH3522	AH3522 BRPS (South Pole to the Part Marking Side) BRPS (North Pole to the Part Marking Side)		2	10	25	Gauss	Open-Drain
			-25	-10	-2	-	
	Вну (Bopx - Brpx)) Hysteresis (Note 13)		10	19		
	B _{OPS} (South Pole to the Part Marking Side)	Operation Point	20	40	60		
	B _{OPN} (North Pole to the Part Marking Side)	Operation Point	-60	-40	-20		
AH3524	BRPS (South Pole to the Part Marking Side)	Release Point	10	25	45	Gauss	Open-Drain
	B _{RPS} (North Pole to the Part Marking Side)	Release F Ulfit	-45	-25	-10		
	Вну (Bopx - Brpx)	Hysteresis (Note 13)	9	15	22		

Notes: 11. When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the startup time of 10µs typical from the operating voltage reaching 3V.

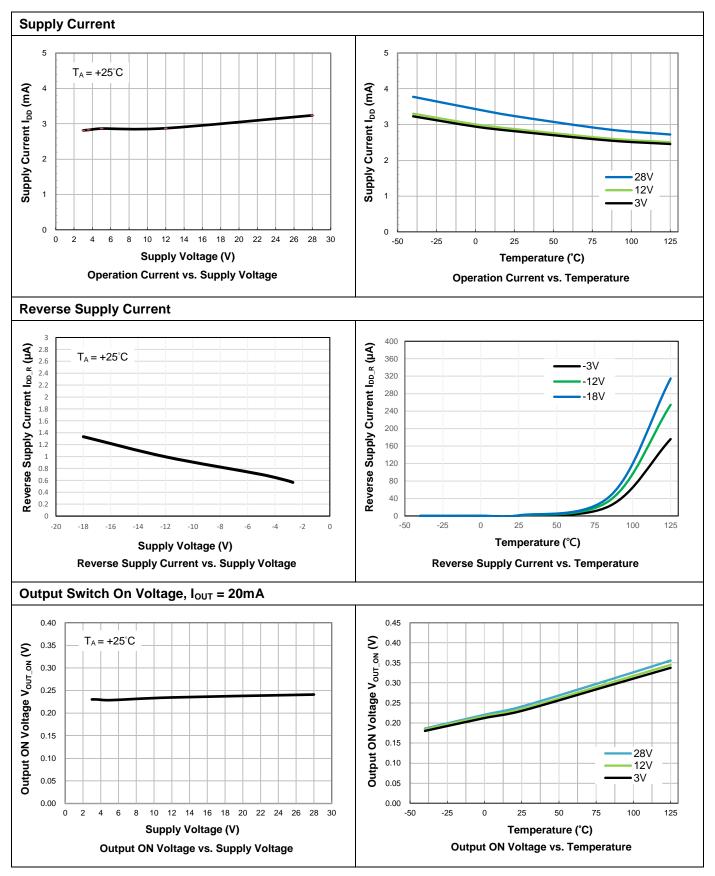
12. Typical values are defined at $T_A = +25^{\circ}$ C, $V_{DD} = 12$ V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control, and characterization.

13. Maximum and minimum hysteresis is guaranteed by design, process control, and characterization.



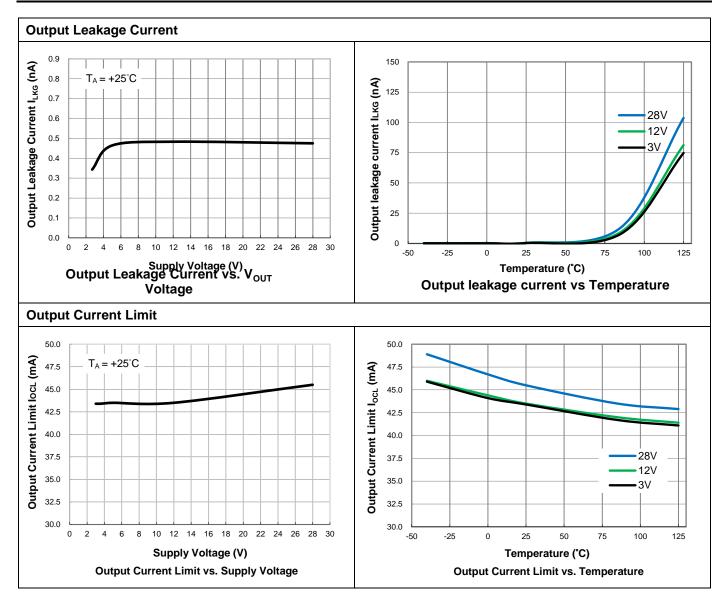


Typical Operating Characteristics



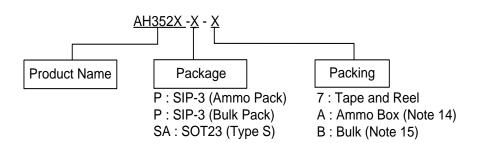


Typical Operating Characteristics (continued)





Ordering Information

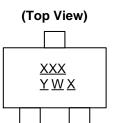


Part Number	Baakaga Cada	Package	Part Number Suffix	Pac	king
Fait Nulliger	Package Code	Fackage	Fait Number Sumx	Qty.	Carrier
AH3522-P-A	Р	SIP-3 (Ammo Pack)	-A	4,000	Ammo Box
AH3522-P-B	Р	SIP-3 (Bulk Pack)	-B	1,000	Bulk
AH3522-SA-7	SA	SOT23 (Type S)	-7	3,000	7" Tape & Reel
AH3524-P-A	Р	SIP-3 (Ammo Pack)	-A	4,000	Ammo Box
AH3524-P-B	Р	SIP-3 (Bulk Pack)	-B	1,000	Bulk
AH3524-SA-7	SA	SOT23 (Type S)	-7	3,000	7" Tape & Reel

Notes: 14. Ammo Box is for SIP-3 Spread Lead. 15. Bulk is for SIP-3 Straight Lead.

Marking Information

(1) Package Type: SOT23 (Type S)



XXX : Identification Code

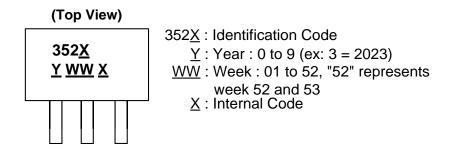
- <u>Y</u>: Year 0 to 9 (ex: 3 = 2023)
- \underline{W} : Week : A to Z : week 1 to 26; a to z : week 27 to 52; z represents week 52 and 53
- X : Internal Code

Part Number	Package	Identification Code
AH3522-SA-7	SOT23 (Type S)	S6A
AH3524-SA-7	SOT23 (Type S)	S6C



Marking Information (continued)

(2) Package Type: SIP-3 (Ammo Pack)/SIP-3 (Bulk Pack)



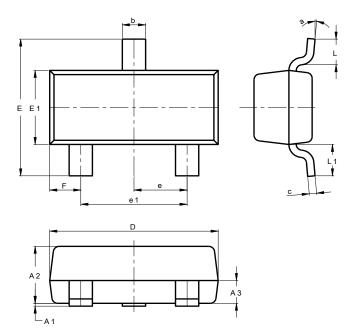
Part Number	Package	Identification Code
AH3522-P-A	SIP-3 (Ammo Pack)	3522
AH3522-P-B	SIP-3 (Bulk Pack)	3522
AH3524-P-A	SIP-3 (Ammo Pack)	3524
AH3524-P-B	SIP-3 (Bulk Pack)	3524



Package Outline Dimensions (All dimensions in mm.)

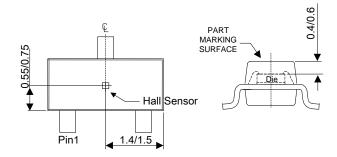
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT23 (Type S)



	SOT23	(Type S)
Dim	Min	Max	Тур
A1	0.013	0.10	0.05
A2	0.90	1.025	1.00
A3	0.375	0.425	0.40
b	0.37	0.51	0.40
C	0.10	0.18	0.125
D	2.80	3.00	2.90
ш	2.30	2.50	2.40
E1	1.20	1.40	1.30
e	0.89	1.03	0.915
e1	1.78	2.05	1.83
F	0.45	0.60	0.535
L1	0.45	0.61	0.55
L	0.25	0.55	0.40
а	0°	8°	
All	Dimens	ions in	mm

Min/Max



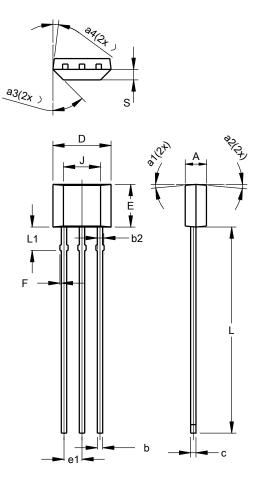
Sensor Location



Package Outline Dimensions (All dimensions in mm.) (continued)

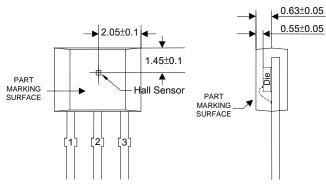
Please see http://www.diodes.com/package-outlines.html for the latest version.

(2) Package Type: SIP-3 (Bulk Pack)



S	IP-3 (Bu	Ik Pack	()
Dim	Min	Max	Тур
Α	1.40	1.60	1.50
b	0.33	0.43	0.38
b2	0.40	0.508	0.46
С	0.35	0.41	0.38
D	3.90	4.30	4.10
Е	2.80	3.20	3.00
e1	1.24	1.30	1.27
F	0.00	0.20	
J	2	.62 REF	-
L	14.00	15.00	14.50
L1	1.55	1.75	1.65
S	0.63	0.84	0.74
a1			5°
a2			5°
a3			45°
a4			3°
All [Dimensi	ons in	mm

Min/Max



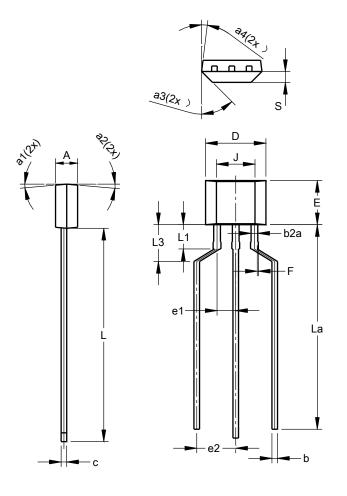
Sensor Location



Package Outline Dimensions (All dimensions in mm.) (continued)

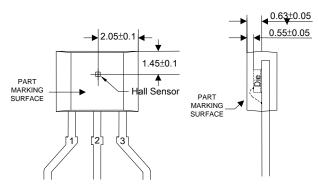
Please see http://www.diodes.com/package-outlines.html for the latest version.

(3) Package Type: SIP-3 (Ammo Pack)



<u> </u>	SIF					
	(Ammo Pack)					
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
b	0.33	0.43	0.38			
b2a	0.40	0.52	0.46			
C	0.35	0.41	0.38			
D	3.90	4.30	4.10			
E	2.80	3.20	3.00			
e1	1.24	1.30	1.27			
e2	2.40	2.90	2.65			
F	0.00	0.20				
J	2	.62 REF	-			
L	14.00	15.00	14.50			
La	12.90	14.90	13.90			
L1	1.55	1.75	1.65			
L3	2.00	3.00	2.50			
s	0.63	0.84	0.74			
a1			5°			
a2			5°			
a3			45°			
a4			3°			
All [Dimensi	ons in	mm			

Min/Max



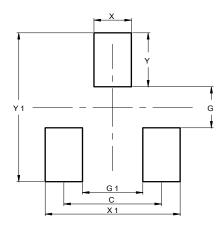
Sensor Location



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Package Type: SOT23 (Type S)



Dimensions	Value (in mm)
С	1.830
G	0.800
G1	1.130
Х	0.700
X1	2.530
Y	1.050
Y1	2.900

Mechanical Data

- Moisture Sensitivity: SOT23 (Type S) Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: SIP-3 (Ammo Pack)/SIP-3 (Bulk Pack) 0.077 grams (Approximate) SOT23 (Type S) – 0.009 grams (Approximate)



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